HN62304B Series HN62324B Series

T-46-13-15

524288-Word × 8-Bit CMOS Mask Programmable ROM

HN62304B, HN62324B Series is a 4-Mbit CMOS maskprogramable ROM organized as 524288-word x 8-bits. It can be operated with a battery because of low power consumption. The large capacity of 4M bits is optimum for a kanji character generator.

Features

- Single 5 V
- Wired OR is permitted for the output in three states
- TTL compatible
- Address access time: 150/200 ns (max.)
- Low power: Active Standby

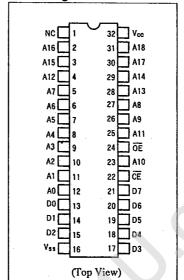
100 mW (typ) 5 μW (typ)

Byte-Wide Data Organization

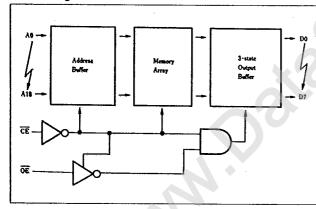
Ordering information

| Type No. | Address Access Time | Package |
|-----------|---------------------|----------------|
| HN62304BP | 200 ns | 600 mil 32-pin |
| HN62324BP | 150 ns | plastic DIP |
| HN62304BF | 200 ns | 32-pin |
| HN62324BF | 150 ns | plastic SOP |

Pin Arrangement



Block Diagram





(1) HITACHI

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Absolute Maximum Ratings

| T-46-13-1 | 5 | 5 | E | į | | | | | | l | ĺ | | | | • | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | , | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | , | , | | | | | | | | | | | | | | | | | | , | | | | | | | | | |
|-----------|---|---|---|---|--|--|--|--|--|---|---|--|--|--|---|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|---|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|---|---|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|---|--|--|--|--|--|--|--|--|--|
|-----------|---|---|---|---|--|--|--|--|--|---|---|--|--|--|---|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|---|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|---|---|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|--|---|--|--|--|--|--|--|--|--|--|

| Item | Symbol | Rating | Unit |
|------------------------|--------|-------------------|------|
| Power supply voltage*1 | Vcc | -0.3 to +7.0 | V |
| Terminal voltage*1 | VT | -0.3 to Vcc + 0.3 | V |
| Operating temperature | Topr | 0 to +70 | °C |
| Storage temperature | Tstg | -55 to +125 | °C |
| Bias temperature | Tbias | -20 to +85 | °C |

Note: •1. With respect to Vss.

Recommended Operating Conditions (Vss = 0 V, Ta = $0 \text{ to } +70 ^{\circ}\text{C}$)

| Item | Symbol | Min | Тур | Max | Unit |
|----------------------|------------------|------|-----|-----------|----------|
| Power supply voltage | Vcc | 4.5 | 5.0 | 5.5 | V |
| T | Vи | 2.2 | | Vcc + 0.3 | <u> </u> |
| Input voltage | V _E , | -0.3 | | 0.8 | ٧ |

DC Characteristics (VCC = $5 \text{ V} \pm 10\%$, Vss = 0 V, Ta = $0 \text{ to } +70^{\circ}\text{C}$)

| Item | | Symbol | Min | Max | Unit | Test Conditions |
|----------------------|---------|--------|-----|-----|------|---|
| Power supply current | Active | Icc | | 50 | mA | Vcc = 5.5 V, Idout = 0 mA, trc = Min |
| rower suppry cuttent | Standby | IsB | | 30 | μΑ | $Vcc = 5.5 \text{ V}, \overline{CE} \ge Vcc - 0.2 \text{ V}$ |
| Input leak current | | Ilul | | 10 | μΑ | $V_{IN} = 0$ to V_{CC} |
| Output leak current | | Lol | | 10 | μΑ | $\overrightarrow{CE} = 2.2 \text{ V}, \overrightarrow{V} \text{OUT} = 0 \text{ to VCC}$ |
| 0 | | Vон | 2.4 | | V | $I_{OH} = -205 \mu A$ |
| Output voltage | | Vol | | 0.4 | V | IoL = 1.6 mA |

Capacitance (Vcc = 5 V \pm 10%, Vss = 0 V, Ta = 25°C, Vin = 0 V, f = 1 MHz)

| Item | Symbol | Min | Max | Unit |
|----------------------|--------|-----|-----|------|
| Input capacitance•1 | Cin | | 15 | pF |
| Output capacitance 1 | Cout | _ | 15 | pF |

Note: •1. This parameter is sampled and not 100% tested.

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AC Operating Characteristics (VCC = 5 V \pm 10%, Vss = 0 V, Ta = 0 to +70°C) **Test Conditions**

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Input pulse level: 0.8 to VO timing reference level: 1.5 V

0.8 to 2.4 V

Output load:

50E D

1 TTL gate + CL = 100 pF

Input rise/fall time:

10 ns

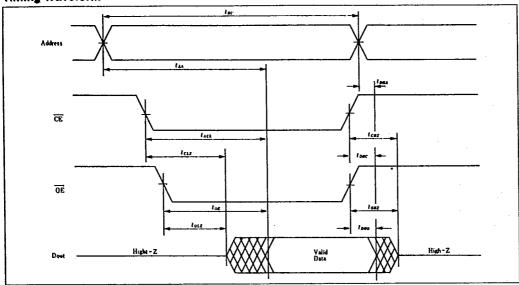
(including jig capacitance)

| Item | Symbol | HN62 | 2324B | HN62 | 2304B | |
|-------------------------------|-------------|--------------|-------|------|-------|-----|
| Alent | Syllibol | Min | Max | Min | Max | Uni |
| Cycle time | trc | 150 | _ | 200 | | ns |
| Address access time | taa | - | 150 | | 200 | ns |
| CE access time | tace | | 150 | - | 200 | ns |
| OE access time | toe | | 70 | | 100 | ns |
| Output Hold Time from Address | s | | | | | |
| Change | TDHA | • 0 | | 0 | | ns |
| Output Hold Time from CE | tonc | 0 | | 0 . | | ns |
| Output Hold Time from OE | рно | 0 | _ | 0 | _ | ns |
| CE to Output in High Z | tcHz*1 | | 70 | | 70 | ns |
| OE to Output in High Z | toHz*1 | _ | 70 | | 70 | ns |
| CE to Output in Low Z | tcl.z | 10 | | 10 | | ns |
| OE to Output in Low Z | tolz | 10 | | 10 | | ns |

*1 tcHz and toHz define the time at which the output goes to the high impedance state and is not referenced to output voltage level.

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Timing Waveform



Notes: 1. tDHA, tDHC, tDHO;

Determined by whichever is faster. Determined by whichever is slower.

2. taa, tace, toe; 3. ICLZ, IOLZ;

Determined by whichever is slower.